



Improved Quad CMOS Analog Switches

DESCRIPTION

The DG308B, DG309B analog switches are highly improved versions of the industry-standard DG308A, DG309. These devices are fabricated in Vishay Siliconix' proprietary silicon gate CMOS process, resulting in lower on-resistance, lower leakage, higher speed, and lower power consumption.

These quad single-pole single-throw switches are designed for a wide variety of applications in telecommunications, instrumentation, process control, computer peripherals, etc.

An improved charge injection compensation design minimizes switching transients. The DG308B and DG309B can handle up to ± 22 V input signals. An epitaxial layer prevents latchup.

All devices feature true bi-directional performance in the on condition, and will block signals to the supply levels in the off condition.

The DG308B is a normally open switch and the DG309B is a normally closed switch. (see Truth Table.)

FEATURES

- ± 22 V supply voltage rating
- CMOS compatible logic
- Low on-resistance - $R_{DS(on)}$: $45\ \Omega$
- Low leakage - $I_{D(on)}$: $20\ \text{pA}$
- Single supply operation possible
- Extended temperature range
- Fast switching - t_{ON} : $< 200\ \text{ns}$
- Low glitching - Q : $1\ \text{pC}$

BENEFITS

- Wide analog signal range
- Simple logic interface
- Higher accuracy
- Minimum transients
- Reduced power consumption
- Superior to DG308A, DG309
- Space savings (TSSOP)

APPLICATIONS

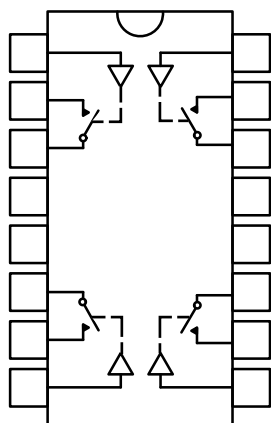
- Industrial instrumentation
- Test equipment
- Communications systems
- Disk drives
- Computer peripherals
- Portable instruments
- Sample-and-hold circuits



RoHS*
COMPLIANT

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

DG308B



TRUTH TABLE

Logic	DG308B	DG309B
0	OFF	ON
1	ON	OFF

Logic "0" ≤ 3.5 V

Logic "1" ≥ 11 V

* Pb containing terminations are not RoHS compliant, exemptions may apply

DG308B, DG309B

Vishay Siliconix



ORDERING INFORMATION

Temp. Range	Package	Part Number
- 40 °C to 85 °C	16-Pin PlasticDIP	DG308BDJ DG308BDJ-E3
		DG309BDJ DG309BDJ-E3
	16-Pin Narrow SOIC	DG308BDY DG308BDY-E3 DG308BDY-T1 DG308BDY-T1-E3
		DG309BDY DG309BDY-E3 DG309BDY-T1 DG309BDY-T1-E3
	16-Pin TSSOP	DG308BDQ DG308BDQ-E3 DG308BDQ-T1 DG308BDQ-T1-E3
		DG309BDQ DG309BDQ-E3 DG309BDQ-T1 DG309BDQ-T1-E3

ABSOLUTE MAXIMUM RATINGS

Parameter		Limit	Unit
Voltages Referenced, V+ to V-		44	V
GND		25	
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Current, Any Terminal		30	mA
Peak Current, S or D (Pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage Temperature	(AK Suffix)	- 65 to 150	°C
	(DJ, DY and DQ Suffix)	- 65 to 125	
Power Dissipation (Package) ^b	16-Pin Plastic DIP ^c	470	mW
	16-Pin Narrow SOIC and TSSOP ^d	640	
	16-Pin CerDIP ^e	900	

Notes:

- Signals on S_X, D_X, or IN_X exceeding V₊ or V₋ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads welded or soldered to PC board.
- Derate 6.5 mW/°C above 75 °C.
- Derate 7.6 mW/°C above 75 °C.
- Derate 12 mW/°C above 75 °C.



SPECIFICATIONS ^a									
Parameter	Symbol	Test Conditions Unless Specified V ₊ = 15 V, V ₋ = - 15 V V _{IN} = 11 V, 3.5 V ^f	Temp. ^b	Typ. ^c	A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		- 15	15	- 15	15	V
Drain-Source On-Resistance	R _{DS(on)}	V _D = ± 10 V, I _S = 1 mA	Room Full	45		85 100		85 100	Ω
R _{DS(on)} Match	ΔR _{DS(on)}		Room	2					%
Source Off Leakage Current	I _{S(off)}	V _S = ± 14 V, V _D = ± 14 V	Room Full	± 0.01	- 0.5 - 20	0.5 20	- 0.5 - 5	0.5 5	nA
Drain Off Leakage Current	I _{D(off)}	V _D = ± 14 V, V _S = ± 14 V	Room Full	± 0.01	- 0.5 - 20	0.5 20	- 0.5 - 5	0.5 5	
Drain On Leakage Current	I _{D(on)}	V _S = V _D = ± 14 V	Room Full	± 0.02	- 0.5 - 40	0.5 40	- 0.5 - 10	0.5 10	
Digital Control									
Input, Voltage High	V _{INH}		Full		11		11		V
Input, Voltage Low	V _{INL}		Full			3.5		3.5	
Input Current	I _{INH} or I _{INL}	V _{INH} or V _{INL}	Full		- 1	1	- 1	1	μA
Input Capacitance	C _{IN}		Room	5					pF
Dynamic Characteristics									
Turn-On Time	t _{ON}	V _S = 3 V, see figure 2	Room			200		200	ns
Turn-Off Time	t _{OFF}		Room			150		150	
Charge Injection	Q	C _L = 1000 pF, V _g = 0 V, R _g = 0 Ω	Room	1					pC
Source-Off Capacitance	C _{S(off)}	V _S = 0 V, f = 1 MHz,	Room	5					pF
Drain-Off Capacitance	C _{D(off)}		Room	5					
Channel-On Capacitance	C _{D(on)}	V _D = V _S = 0 V, f = 1 MHz	Room	16					
Off-Isolation	OIRR	C _L = 15 pF, R _L = 50 Ω, V _S = 1 V _{RMS} , f = 100 kHz	Room	90					dB
Channel-to-Channel Crosstalk	X _{TALK}		Room	95					
Power Supply									
Positive Supply Current	I ₊	V _{IN} = 0 V or 15 V	Room Full			1 5		1 5	μA
Negative Supply Current	I ₋		Room Full		- 1 - 5		- 1 - 5		
Power Supply Range for Continuous Operation	V _{OP}		Full		± 4	± 22	± 4	± 22	V



SPECIFICATIONS ^a (for Single Supply)									
Parameter	Symbol	Test Conditions Unless Specified V ₊ = 12 V, V ₋ = 0 V V _{IN} = 11 V, 3.5 V ^f	Temp. ^b	Typ. ^c	A Suffix - 55 °C to 125 °C		D Suffix - 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		0	12	0	12	V
Drain-Source On-Resistance	R _{DS(on)}	V _D = 3 V, 8 V, I _S = 1 mA	Room Full	90		160 200		160 200	Ω
Dynamic Characteristics									
Turn-On Time	t _{ON}	V _S = 8 V, see figure 2	Room			300		300	ns
Turn-Off Time	t _{OFF}		Room			200		200	
Charge Injection	Q	C _L = 1 nF, V _{gen} = 6 V, R _{gen} = 0 Ω	Room	4					pC
Power Supply									
Positive Supply Current	I ₊	V _{IN} = 0 V or 12 V	Room Full			1 5		1 5	μA
Negative Supply Current	I ₋		Room Full		- 1 - 5		- 1 - 5		
Power Supply Range for Continuous Operation	V _{OP}		Full		4	44	4	44	V

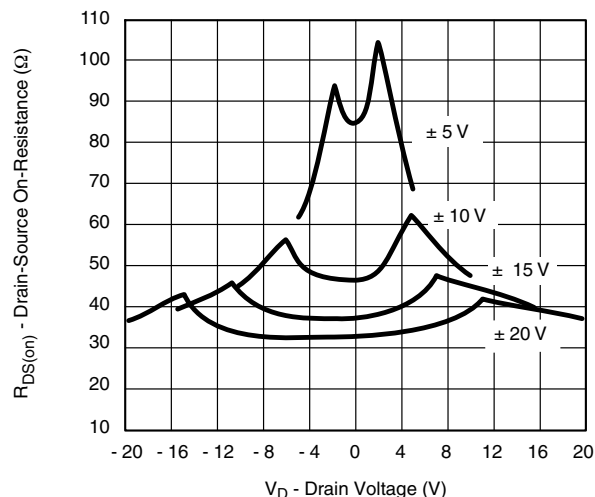
Notes:

- Refer to PROCESS OPTION FLOWCHART .
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.
- V_{IN} = input voltage to perform proper function.

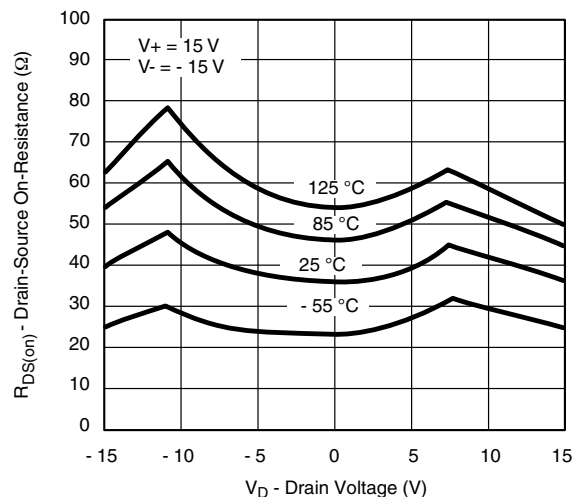
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



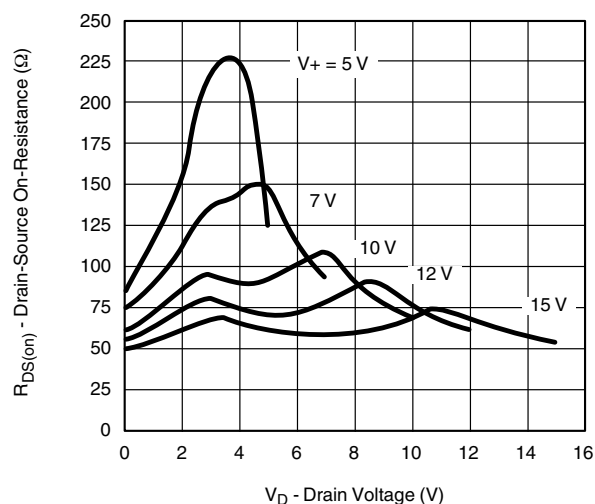
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



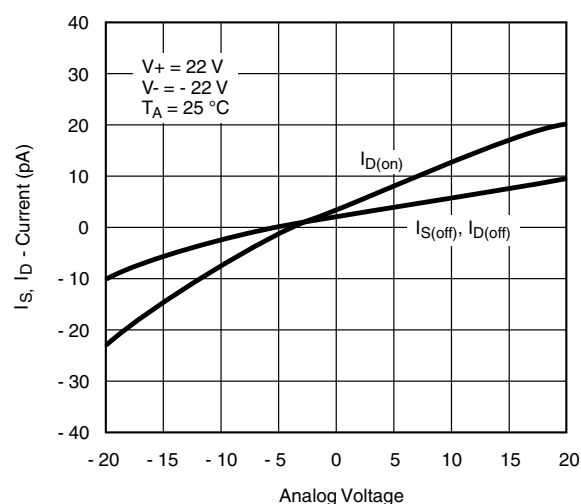
$R_{DS(on)}$ vs. V_D and Power Supply Voltages



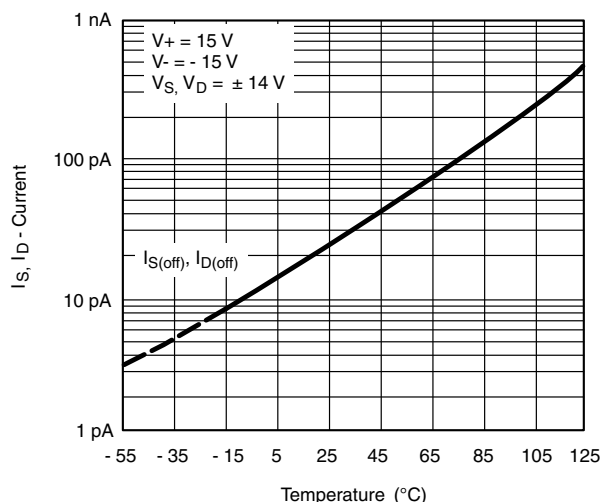
$R_{DS(on)}$ vs. V_D and Temperature



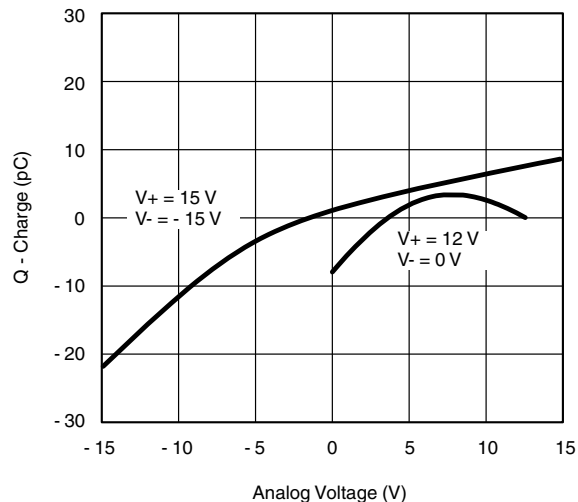
$R_{DS(on)}$ vs. V_D and Single Power Supply Voltages



Leakage Currents vs. Analog Voltage



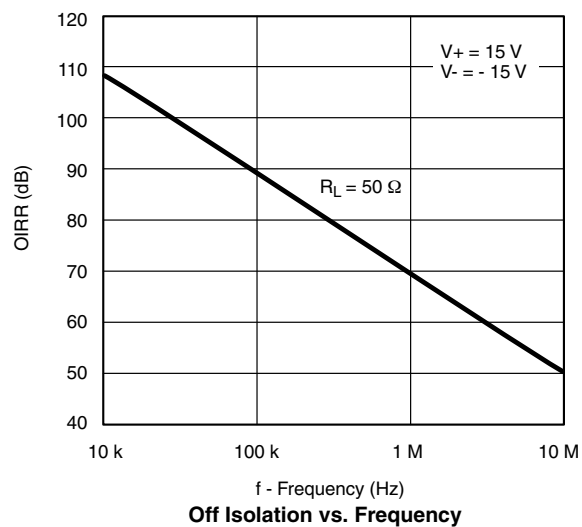
Leakage Currents vs. Temperature



Q_S , Q_D - Charge Injection vs. Analog Voltage



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



SCHEMATIC DIAGRAM (Typical Channel)

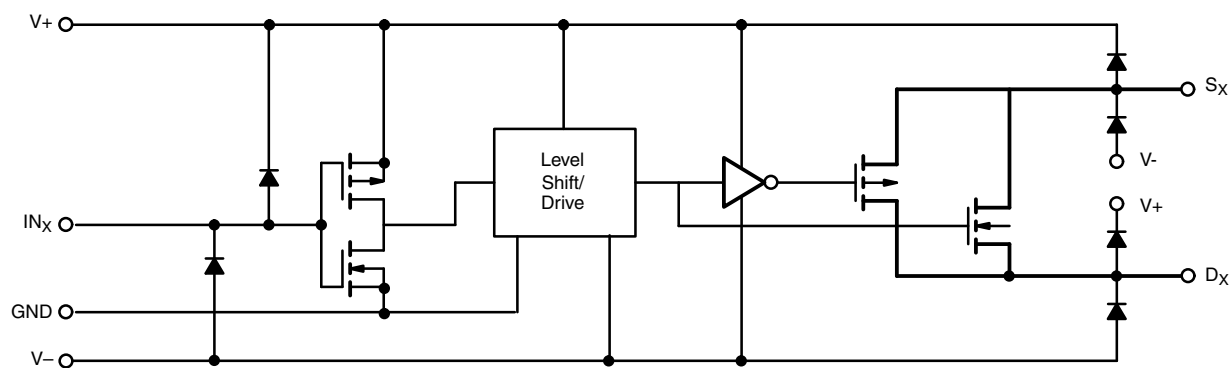


Figure 1.



TEST CIRCUITS

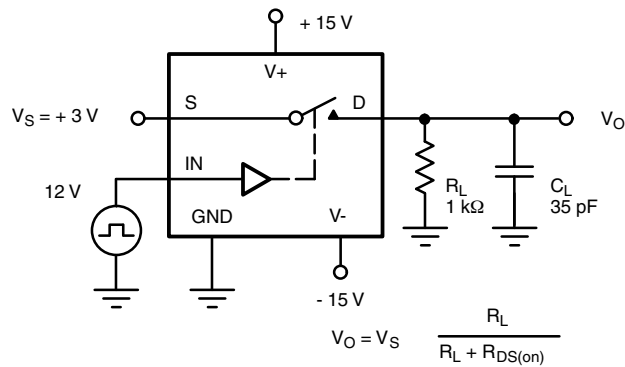


Figure 2. Switching Time

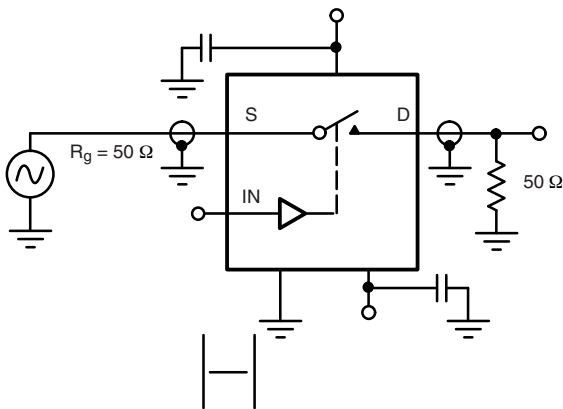
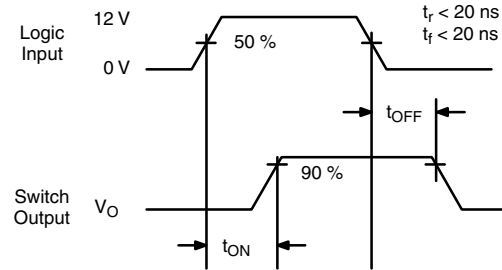


Figure 3. Off Isolation

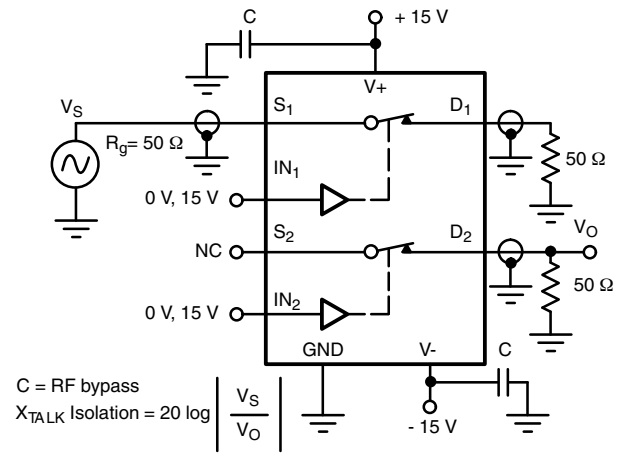


Figure 4. Channel-to-Channel Crosstalk

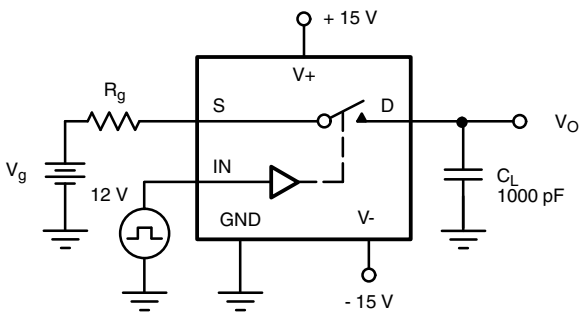
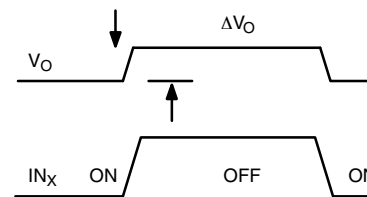


Figure 5. Charge Injection



ΔV_O = measured voltage error due to charge injection
The charge injection in coulombs is $Q = C_L \times \Delta V_O$

APPLICATIONS

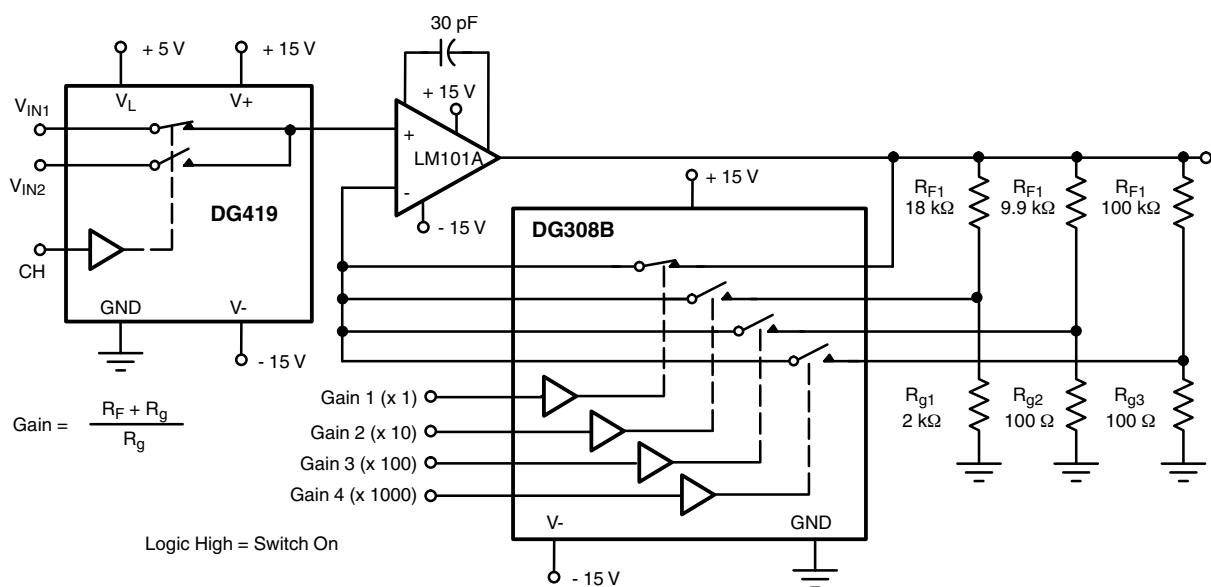


Figure 6. A Precision Amplifier with Digitally Programmable Inputs and Gains

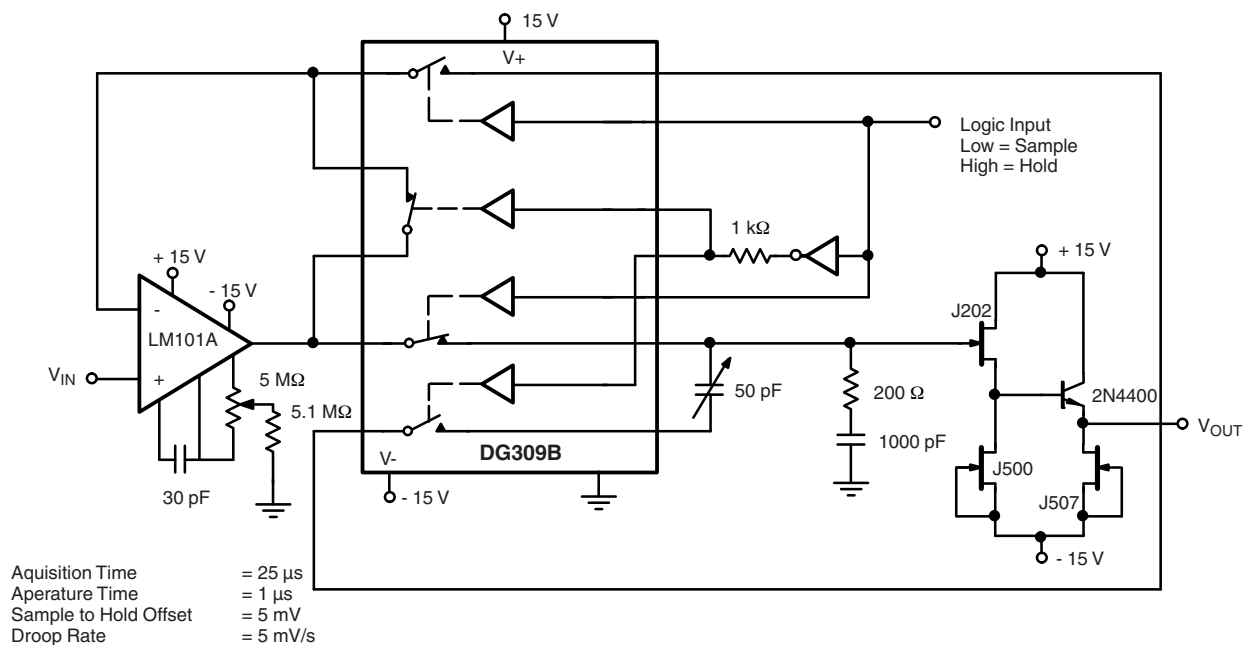
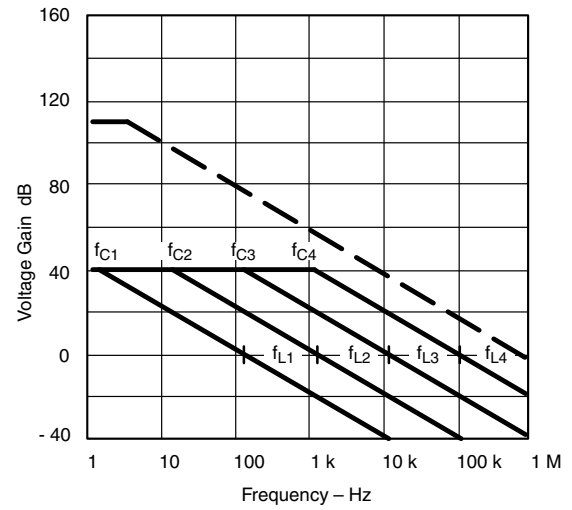
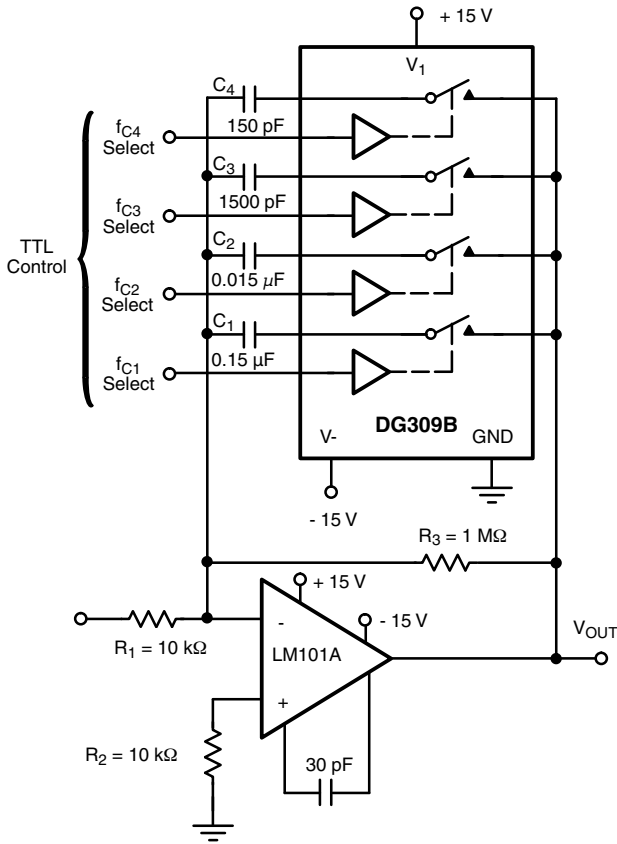


Figure 7. Sample-and-Hold



APPLICATIONS



$$A_L \text{ (Voltage Gain Below Break Frequency)} = \frac{R_3}{R_1} = 100 \text{ (40 dB)}$$

$$f_C \text{ (Break Frequency)} = \frac{1}{2\pi R_3 C_X}$$

$$f_L \text{ (Unity Gain Frequency)} = \frac{1}{2\pi R_1 C_X}$$

$$\text{Max Attenuation} = \frac{R_{DS(on)}}{10 \text{ k}\Omega} \approx -40 \text{ dB}$$

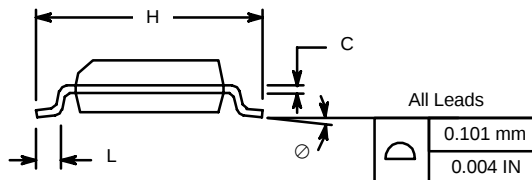
Figure 8. Active Low Pass Filter with Digitally Selected Break Frequency

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SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012

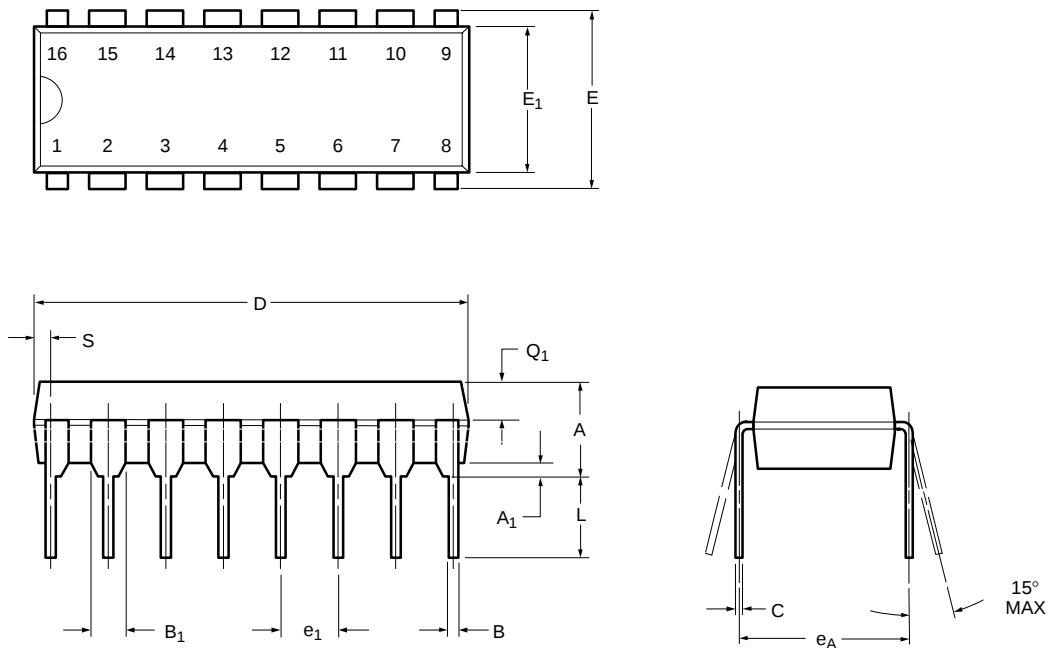


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300



PDIP: 16-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E₁	5.59	7.11	0.220	0.280
e₁	2.29	2.79	0.090	0.110
e_A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060
ECN: S-03946—Rev. D, 09-Jul-01 DWG: 5482				

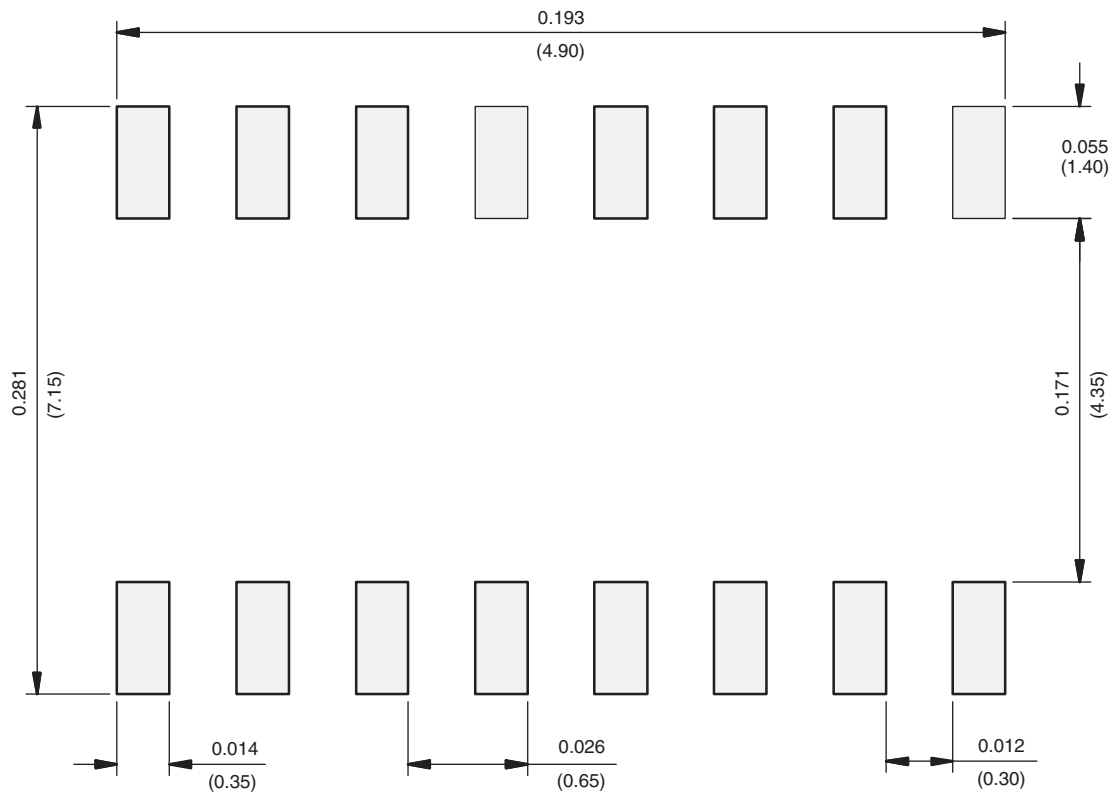
TSSOP: 16-LEAD



Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			



RECOMMENDED MINIMUM PAD FOR TSSOP-16



Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

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